

PS9122

1 Mbps OPEN COLLECTOR OUTPUT TYPE
5-PIN SOP (SO-5), HIGH-SPEED PHOTOCOUPLER

R08DS0256EJ0100
Rev.1.00
Dec 2, 2021

DESCRIPTION

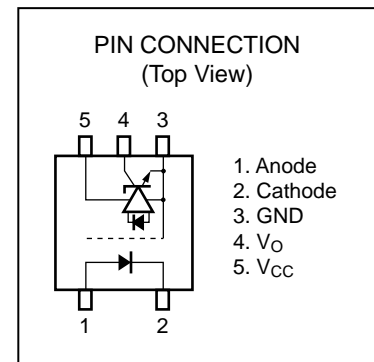
The PS9122 is an optical coupled high-speed, active low type isolator containing an AlGaAs LED on the input side and a photodiode and a signal processing circuit on the output side on one chip.

The PS9122 is a high-speed digital output type photocopler designed specifically for low circuit current.

The PS9122 is in 5-pin plastic SOP (Small Outline Package) and is suitable for high density application.

FEATURES

- Supply Voltage
 - N rank: $V_{CC} = 3.3\text{ V}$
 - L rank: $V_{CC} = 5\text{ V}$
- Pulse width distortion ($|t_{PHL} - t_{PLH}| = 200\text{ ns MAX.}$)
- Small package (SO-5)
- High-speed (1 Mbps)
- High isolation voltage ($BV = 3\ 750\text{ Vr.m.s.}$)
- Open collector output
- Embossed tape product: PS9122-F3: 2 500 pcs/reel
- Pb-Free product
- Safety standards
 - UL : UL1577, Single protection
 - CSA : CAN/CSA-C22.2 No.62368-1, Basic insulation
 - VDE : DIN EN 60747-5-5 (Option)



APPLICATIONS

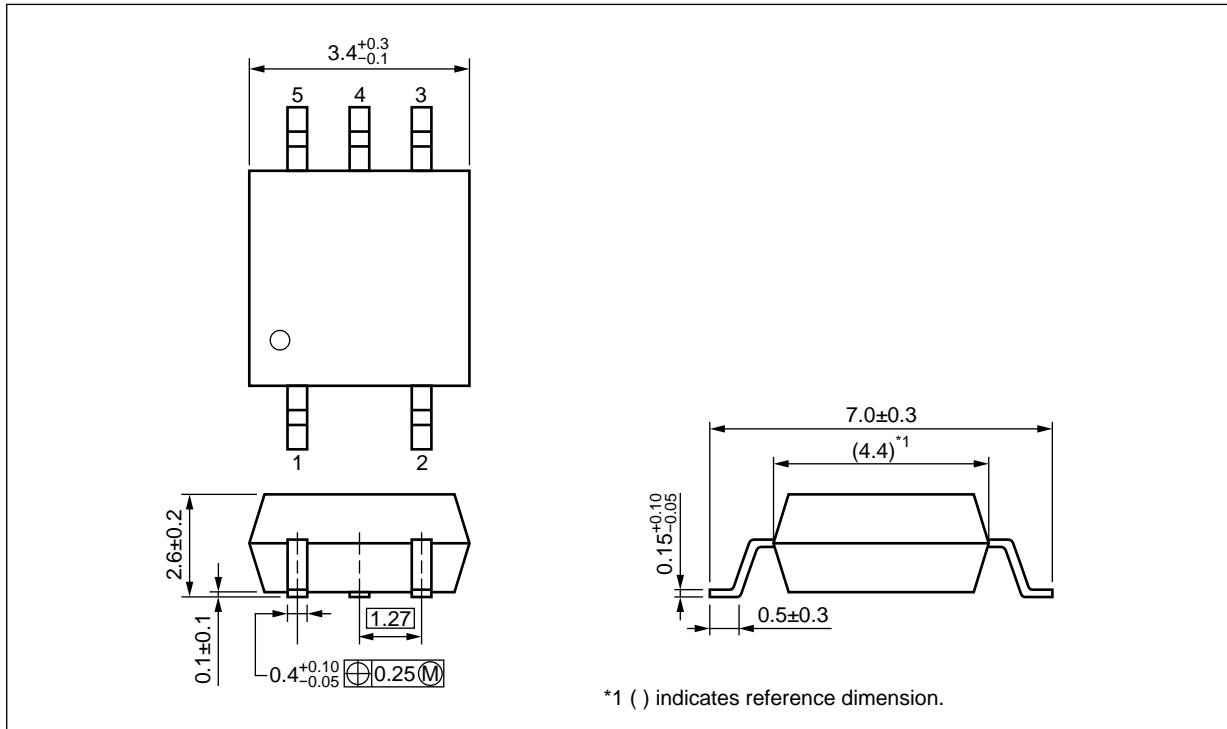
- PoE (Power over Ethernet)
- Measurement equipment
- FA Network

TRUTH TABLE

LED	Output
ON	L
OFF	H

Start of mass production
Oct.2008

PACKAGE DIMENSIONS (UNIT: mm)

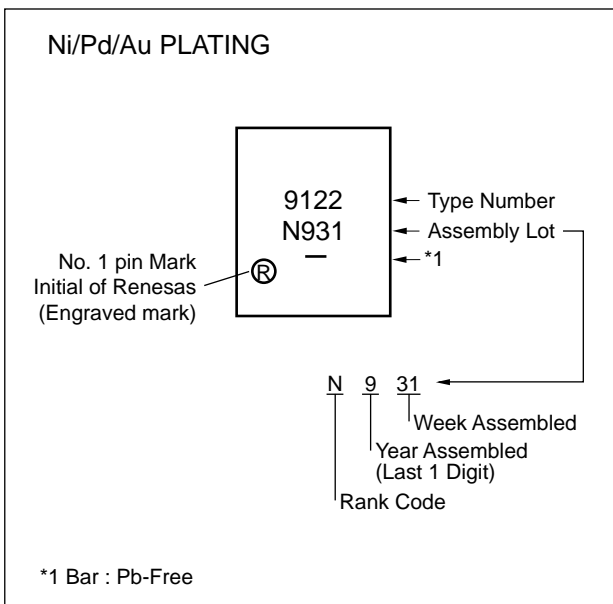


Weight: 0.08g (typ.)

PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	4.2 mm
Outer Creepage Distance	4.2 mm
Isolation Distance	0.2 mm

MARKING EXAMPLE



ORDERING INFORMATION

Part Number	Order Number *4	Rank	Solder Plating Specification	Packing Style	Safety Standards Approval	Application Part Number *1
PS9122	PS9122-AX	N ²	Pb-Free (Ni/Pd/Au)	20 pcs (Tape 20 pcs cut)	Standard products (UL, CSA approved)	PS9122
		L ³				
PS9122-F3	PS9122-F3-AX	N ²		Embossed Tape 2 500 pcs/reel		
		L ³				
PS9122-V	PS9122-V-AX	N ²		20 pcs (Tape 20 pcs cut)	UL, CSA, DIN EN 60747-5-5 approved	
		L ³				
PS9122-V-F3	PS9122-V-F3-AX	N ²		Embossed Tape 2 500 pcs/reel		
		L ³				

Notes*: 1. For the application of the Safety Standard, following part number should be used.

2. N rank: V_{cc} = 3.3 V
3. L rank: V_{cc} = 5 V
4. When specifying rank, please add "/rank" after Order Number.
ex. N rank : PS9122-AX/N

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current *1	I _F	25	mA
	Reverse Voltage	V _R	5	V
Detector	Supply Voltage	V _{CC}	7	V
	Output Voltage	V _O	7	V
	Output Current	I _O	20	mA
	Power Dissipation *2	P _C	40	mW
Isolation Voltage *3		BV	3 750	Vr.m.s.
Operating Ambient Temperature		T _A	- 40 to +100	°C
Storage Temperature		T _{stg}	- 55 to +125	°C

Notes*: 1. Reduced to 0.17 mA/°C at T_A = 25 °C or more.

2. Applies to output pin V_O (collector pin). Reduced to 1.5 mW/°C at T_A = 80 °C or more.

3. AC voltage for 1 minute at T_A = 25 °C, RH = 60% between input and output.

Pins 1-2 shorted together, 3-5 shorted together.

RECOMMENDED OPERATING CONDITIONS

Parameter		Symbol	MIN.	TYP.	MAX.	Unit
Low Level Input Voltage		V _{FL}	0		0.8	V
High Level Input Current		I _{FH}	6.3	10	12.5	mA
Supply Voltage	N rank	V _{CC}	2.7	3.3	3.6	V
	L rank		4.5	5.0	5.5	
TTL (R _L = 1 kΩ, loads)		N			3	
Pull-up Resistor		R _L	330		4 k	Ω

ELECTRICAL CHARACTERISTICS 1: N rank ($T_A = -40$ to $+100$ °C, unless otherwise specified)

Parameter		Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit	
Diode	Forward Voltage	V_F	$I_F = 10$ mA, $T_A = 25$ °C		1.6	1.8	V	
	Reverse Current	I_R	$V_R = 3$ V, $T_A = 25$ °C			10	μA	
	Terminal Capacitance	C_i	$V = 0$ V, $f = 1$ MHz, $T_A = 25$ °C		30		pF	
Detector	High Level Output Current	I_{OH}	$V_{CC} = V_O = 3.3$ V, $V_F = 0.8$ V		1	100	μA	
	Low Level Output Voltage*2	V_{OL}	$V_{CC} = 3.3$ V, $I_F = 5$ mA, $I_{OL} = 10$ mA		0.2	0.6	V	
	High Level Supply Current	I_{CCH}	$V_{CC} = 3.3$ V, $I_F = 0$ mA, $V_O =$ Open			2	mA	
	Low Level Supply Current	I_{CCL}	$V_{CC} = 3.3$ V, $I_F = 10$ mA, $V_O =$ Open			3		
Coupled	Threshold Input Current (H → L)	I_{FHL}	$V_{CC} = 3.3$ V, $V_O = 0.8$ V, $R_L = 350$ Ω		2	5	mA	
	Isolation Resistance	R_{I-O}	$V_{I-O} = 1$ kV _{DC} , $R_H = 40$ to 60 %, $T_A = 25$ °C	10^{11}			Ω	
	Isolation Capacitance	C_{I-O}	$V = 0$ V, $f = 1$ MHz, $T_A = 25$ °C		0.6		pF	
	Propagation Delay Time (H → L)*3	t_{PHL}	$V_{CC} = 3.3$ V, $R_L = 350$ Ω, $I_F = 7.5$ mA, $V_{THHL} = V_{THLH} = 1.5$ V			500	ns	
	Propagation Delay Time (L → H)*3	t_{PLH}				700		
	Rise Time	t_r				60	ns	
	Fall Time	t_f				70		
	Pulse Width Distortion (PWD)*3	$ t_{PHL} - t_{PLH} $					200	ns
	Common Mode Transient Immunity at High Level Output*4	CM_H		$V_{CC} = 3.3$ V, $R_L = 350$ Ω, $T_A = 25$ °C, $I_F = 0$ mA, $V_O > 2.0$ V, $V_{CM} = 1.0$ kV	15	20		kV/μs
	Common Mode Transient Immunity at Low Level Output*4	CM_L		$V_{CC} = 3.3$ V, $R_L = 350$ Ω, $T_A = 25$ °C, $I_F = 7.5$ mA, $V_O < 0.8$ V, $V_{CM} = 1.0$ kV	15	20		

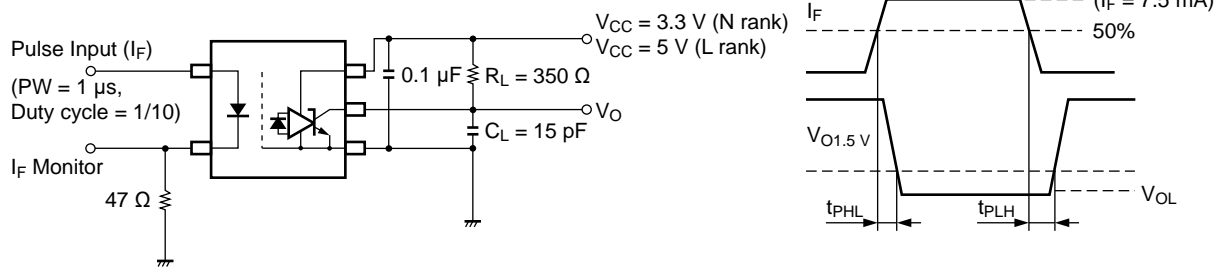
ELECTRICAL CHARACTERISTICS 2: L rank ($T_A = -40$ to $+100$ °C, unless otherwise specified)

Parameter		Symbol	Conditions	MIN.	TYP.* ⁵	MAX.	Unit	
Diode	Forward Voltage	V_F	$I_F = 10$ mA, $T_A = 25$ °C		1.6	1.8	V	
	Reverse Current	I_R	$V_R = 3$ V, $T_A = 25$ °C			10	μA	
	Terminal Capacitance	C_t	$V = 0$ V, $f = 1$ MHz, $T_A = 25$ °C		30		pF	
Detector	High Level Output Current	I_{OH}	$V_{CC} = V_O = 5$ V, $V_F = 0.8$ V		1	100	μA	
	Low Level Output Voltage* ⁶	V_{OL}	$V_{CC} = 5$ V, $I_F = 5$ mA, $I_{OL} = 13$ mA		0.2	0.6	V	
	High Level Supply Current	I_{CCH}	$V_{CC} = 5$ V, $I_F = 0$ mA, $V_O =$ Open			2.5	mA	
	Low Level Supply Current	I_{CCL}	$V_{CC} = 5$ V, $I_F = 10$ mA, $V_O =$ Open			3.5		
Coupled	Threshold Input Current (H → L)	I_{FHL}	$V_{CC} = 5$ V, $V_O = 0.8$ V, $R_L = 350$ Ω		2	5	mA	
	Isolation Resistance	R_{I-O}	$V_{I-O} = 1$ kV _{DC} , $R_H = 40$ to 60 %, $T_A = 25$ °C	10^{11}			Ω	
	Isolation Capacitance	C_{I-O}	$V = 0$ V, $f = 1$ MHz, $T_A = 25$ °C		0.6		pF	
	Propagation Delay Time (H → L) ⁷	t_{PHL}	$V_{CC} = 5$ V, $R_L = 350$ Ω, $I_F = 7.5$ mA, $V_{THHL} = V_{THLH} = 1.5$ V			500	ns	
	Propagation Delay Time (L → H) ⁷	t_{PLH}				700		
	Rise Time	t_r				60	ns	
	Fall Time	t_f				70		
	Pulse Width Distortion (PWD) ⁷	$ t_{PHL} - t_{PLH} $					200	ns
	Common Mode Transient Immunity at High Level Output ⁸	CM_H		$V_{CC} = 5$ V, $R_L = 350$ Ω, $T_A = 25$ °C, $I_F = 0$ mA, $V_O > 2.0$ V, $V_{CM} = 1.0$ kV	15	20		kV/μs
	Common Mode Transient Immunity at Low Level Output ⁸	CM_L		$V_{CC} = 5$ V, $R_L = 350$ Ω, $T_A = 25$ °C, $I_F = 7.5$ mA, $V_O < 0.8$ V, $V_{CM} = 1.0$ kV	15	20		

Notes*: 1,5. Typical values at $T_A = 25\text{ }^\circ\text{C}$.

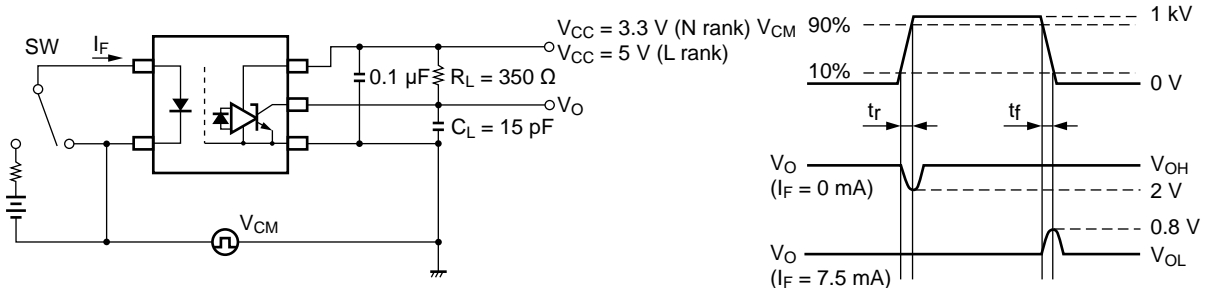
2,6. Because V_{OL} of 2 V or more may be output when LED current input and when output supply of $V_{CC} = 2\text{ V}$ more or less, it is important to confirm the characteristics (operation with the power supply on and off) during design, before using this device

3,7. Test circuit for propagation delay time



Remark: C_L includes probe and stray wiring capacitance.

4,8. Test circuit for common mode transient immunity

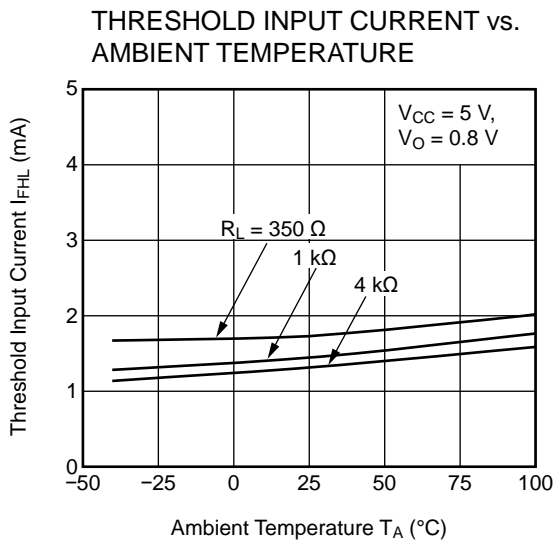
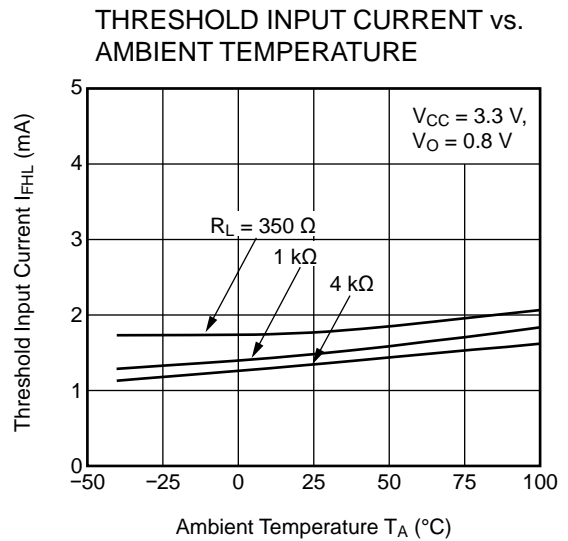
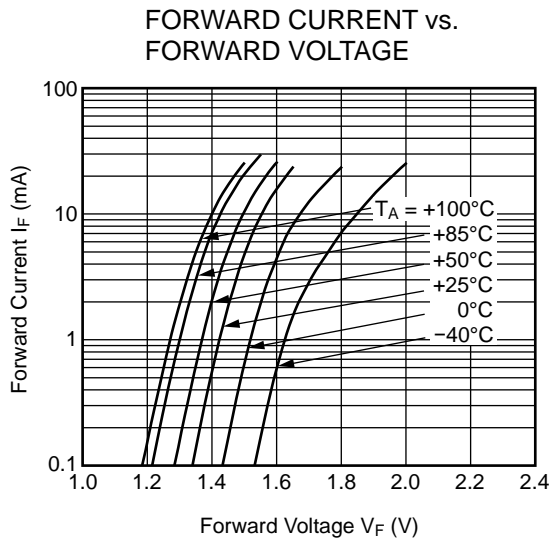
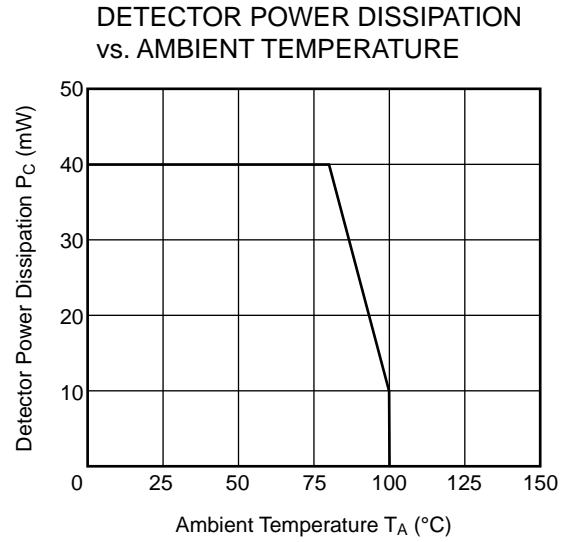
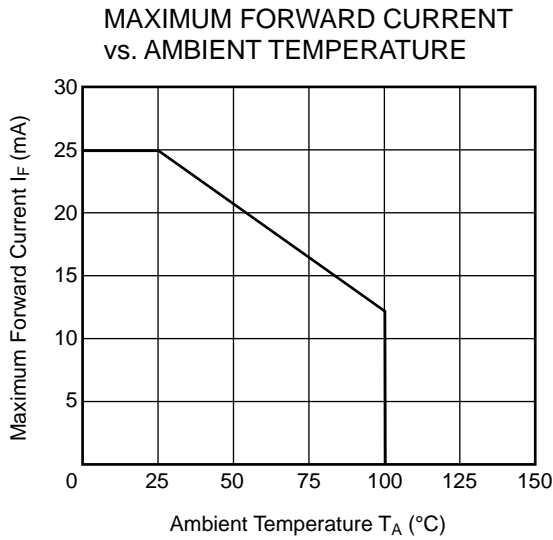


Remark: C_L includes probe and stray wiring capacitance.

USAGE CAUTIONS

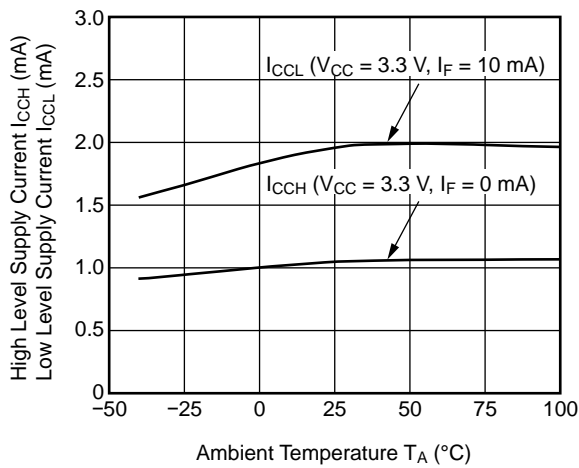
1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
2. By-pass capacitor of more than $0.1\mu\text{F}$ is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocopier and capacitor is no more than 10 mm.
3. Avoid storage at a high temperature and high humidity.
4. Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
5. Do not use fixing agents or coatings containing halogen-based substances.

TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$ unless otherwise specified)

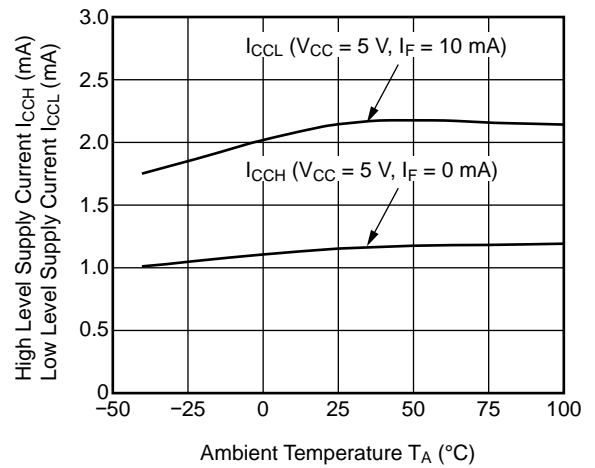


Remark The graphs indicate nominal characteristics.

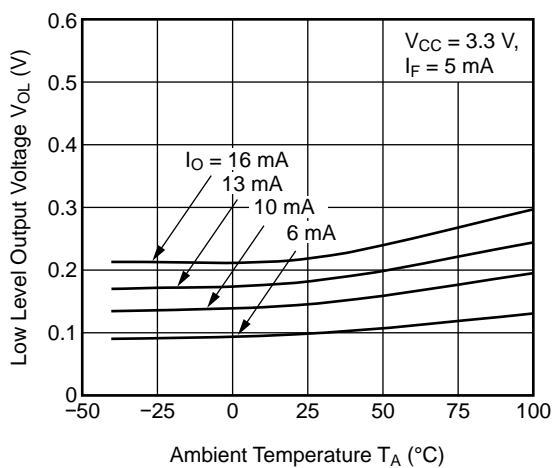
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



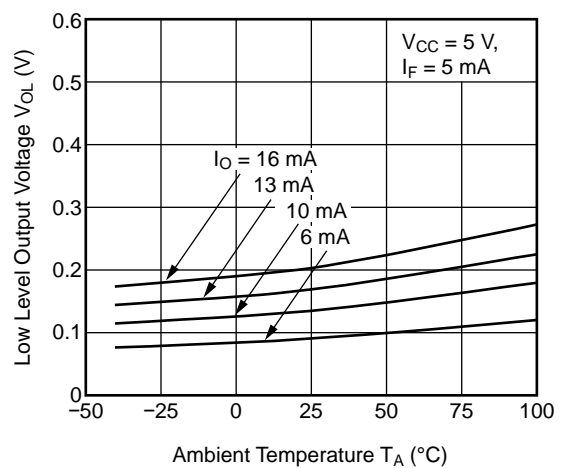
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



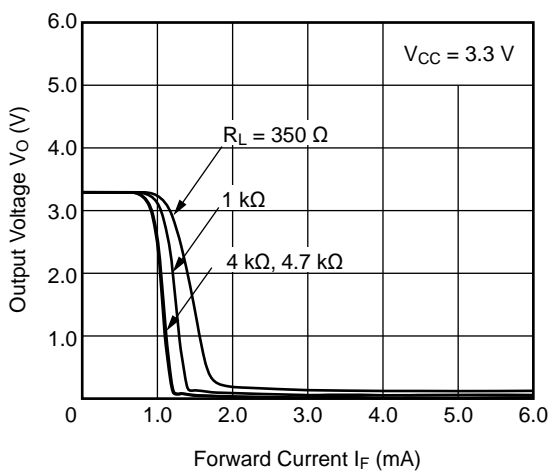
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



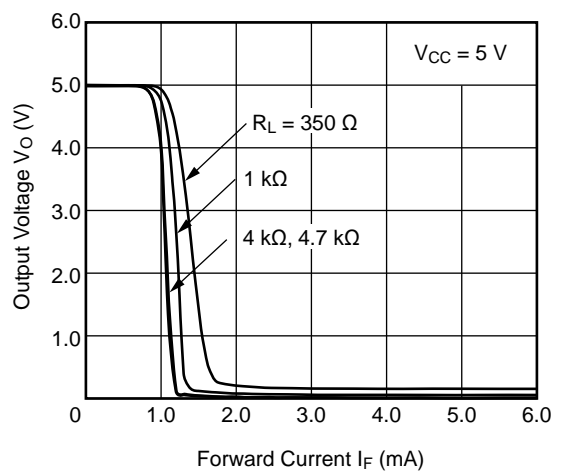
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



OUTPUT VOLTAGE vs. FORWARD CURRENT

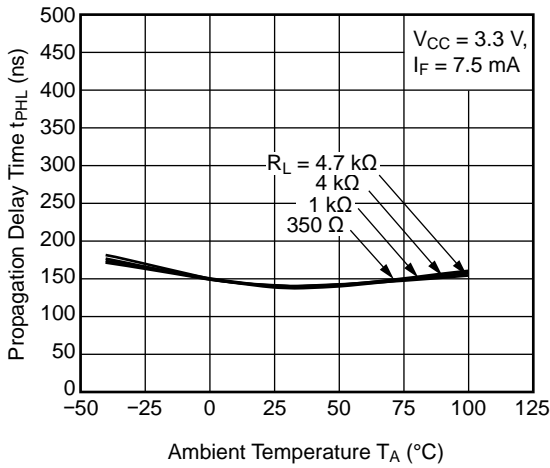


OUTPUT VOLTAGE vs. FORWARD CURRENT

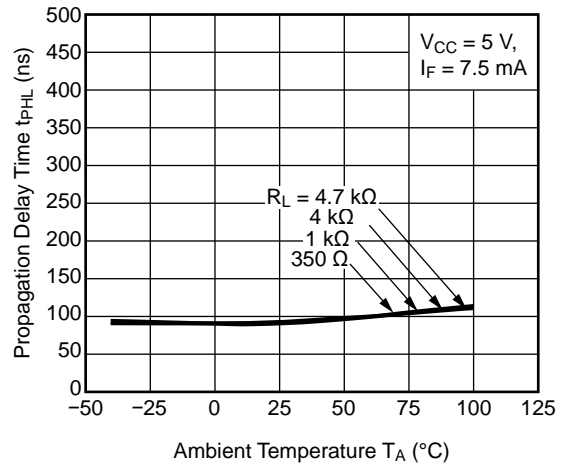


Remark The graphs indicate nominal characteristics.

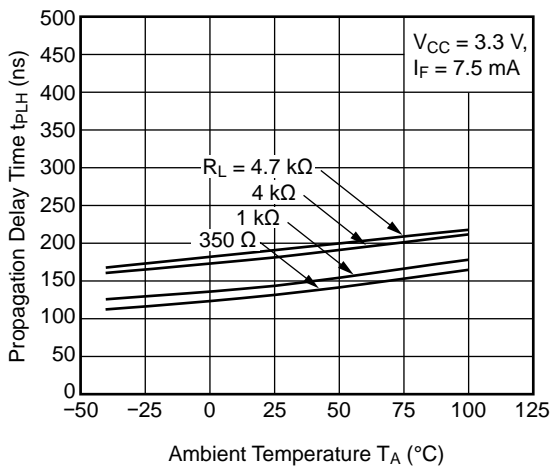
PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



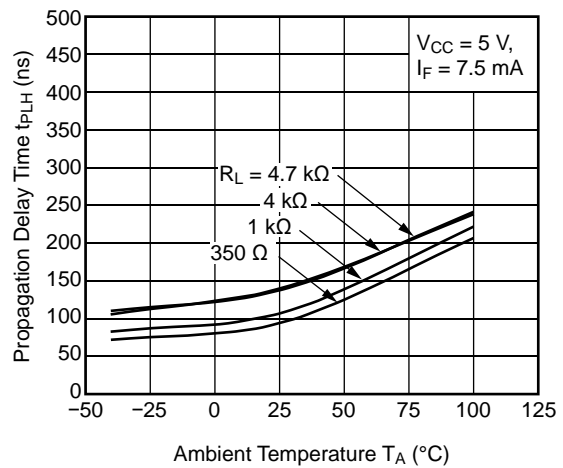
PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



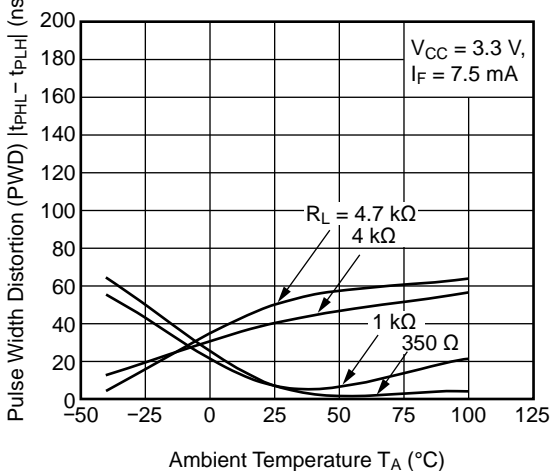
PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



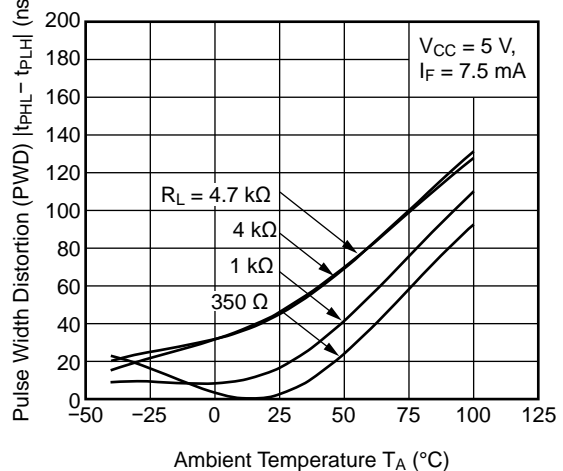
PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



PULSE WIDTH DISTORTION vs. AMBIENT TEMPERATURE

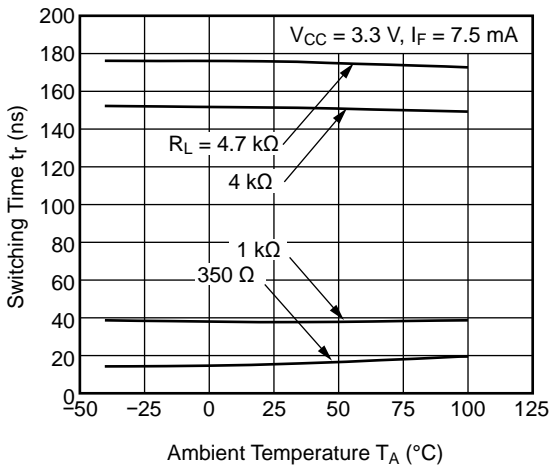


PULSE WIDTH DISTORTION vs. AMBIENT TEMPERATURE

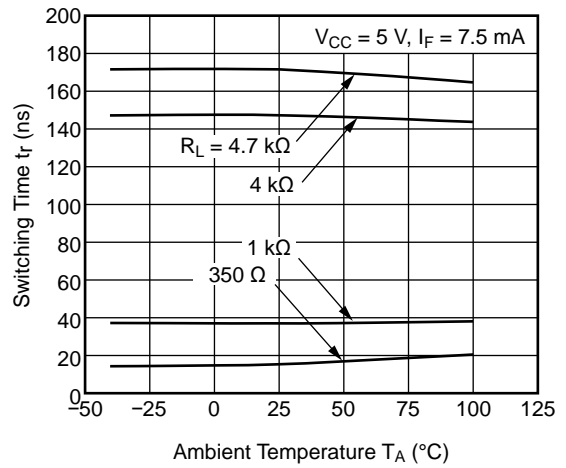


Remark The graphs indicate nominal characteristics.

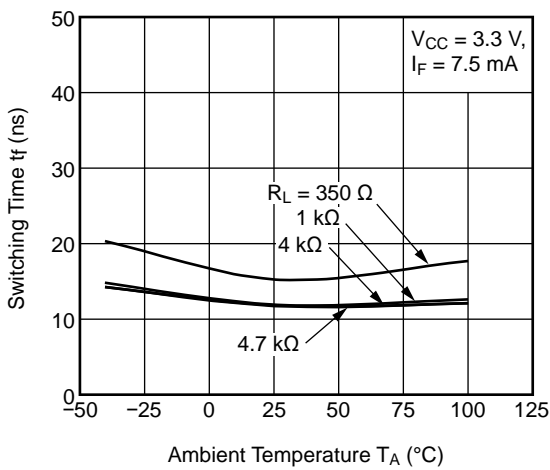
SWITCHING TIME vs. AMBIENT TEMPERATURE



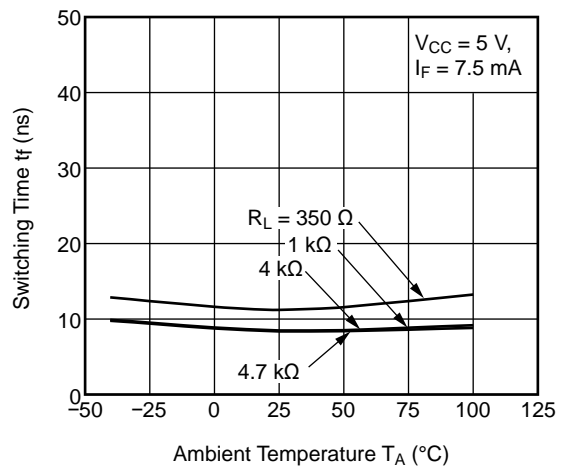
SWITCHING TIME vs. AMBIENT TEMPERATURE



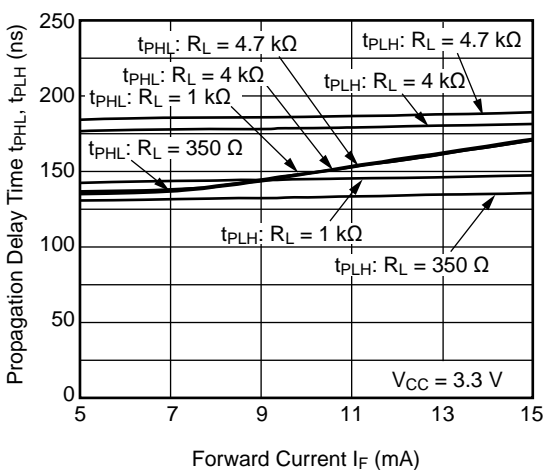
SWITCHING TIME vs. AMBIENT TEMPERATURE



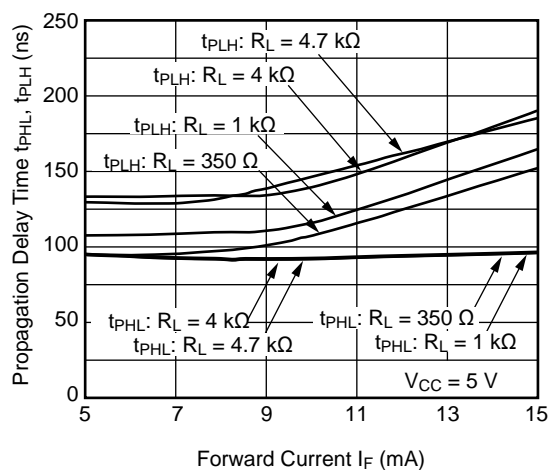
SWITCHING TIME vs. AMBIENT TEMPERATURE



PROPAGATION DELAY TIME vs. FORWARD CURRENT



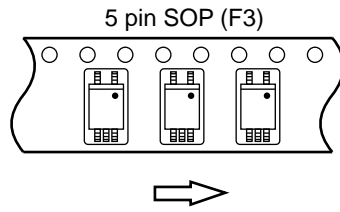
PROPAGATION DELAY TIME vs. FORWARD CURRENT



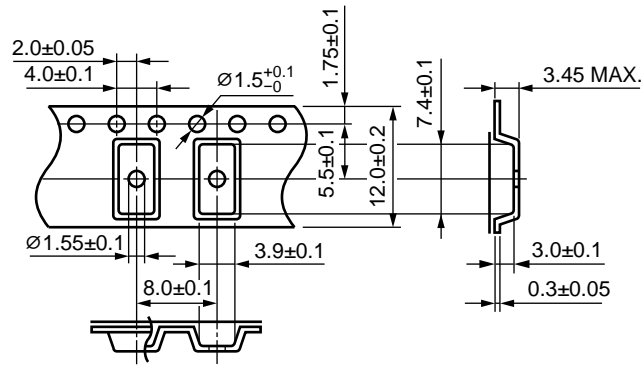
Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

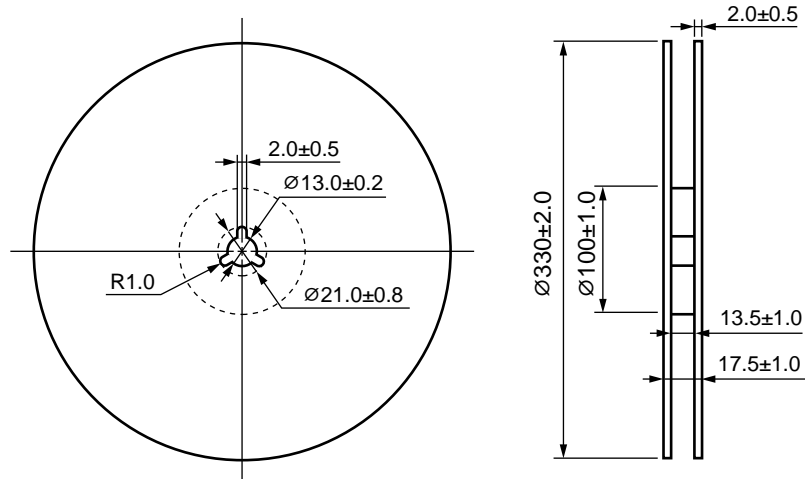
Tape Direction



Outline and Dimensions (Tape)

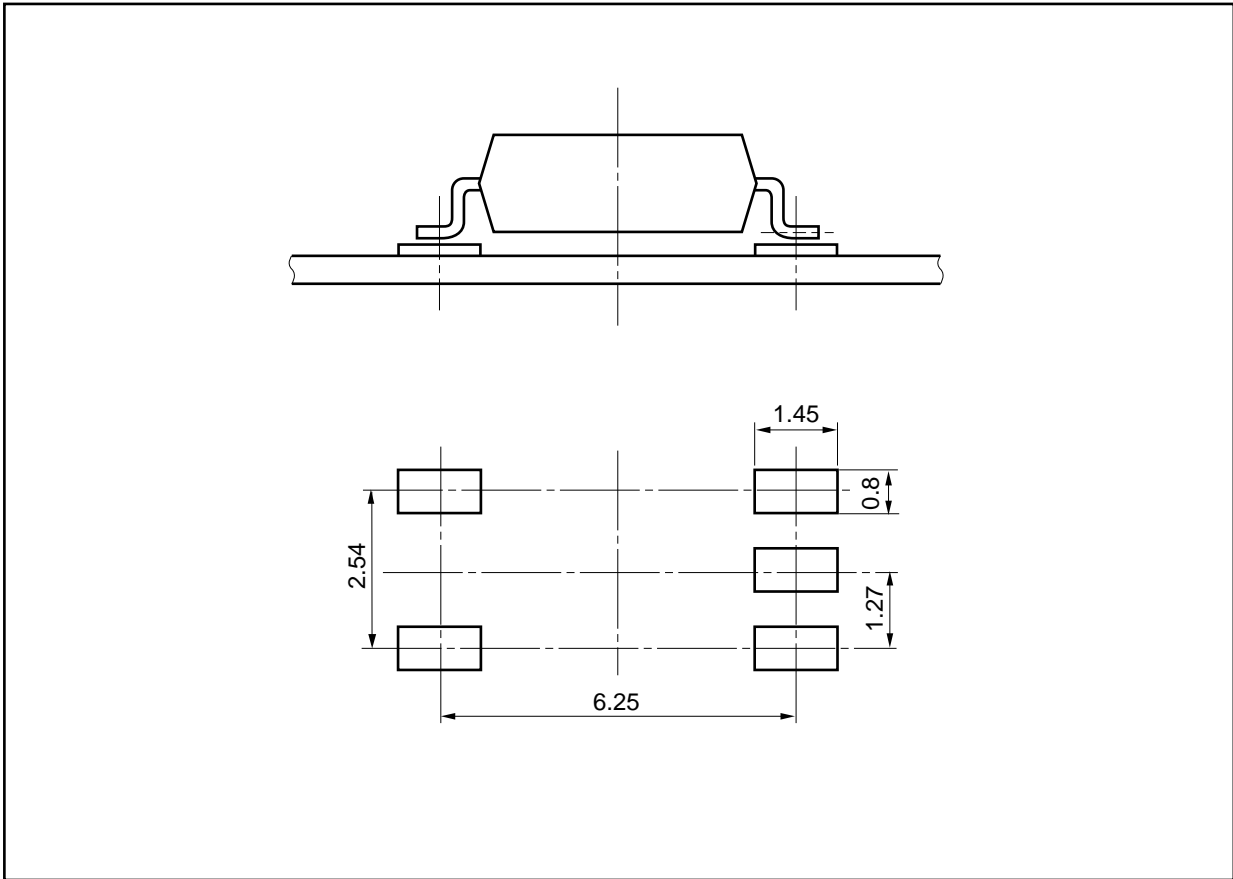


Outline and Dimensions (Reel)



Packing: 2 500 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

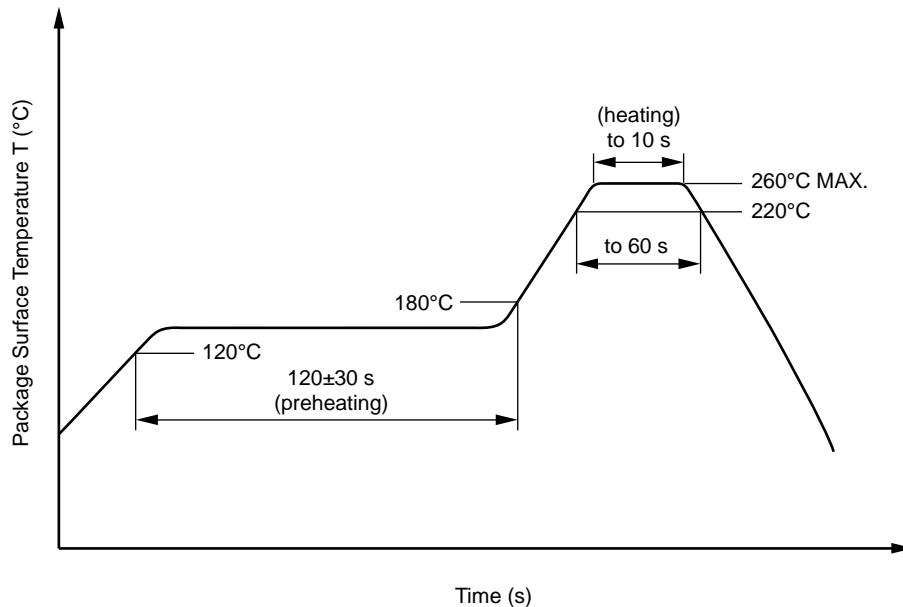
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

- Peak reflow temperature 260 °C or below (package surface temperature)
- Time of peak reflow temperature 10 seconds or less
- Time of temperature higher than 220 °C 60 seconds or less
- Time to preheat temperature from 120 to 180 °C 120 ± 30 s
- Number of reflows Three
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

- Temperature 260 °C or below (molten solder temperature)
- Time 10 seconds or less
- Preheating conditions 120 °C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350 °C or below
- Time (each pins) 3 seconds or less
- Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100 °C

(4) Cautions

- Flux Cleaning
 - Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- Do not use fixing agents or coatings containing halogen-based substances.

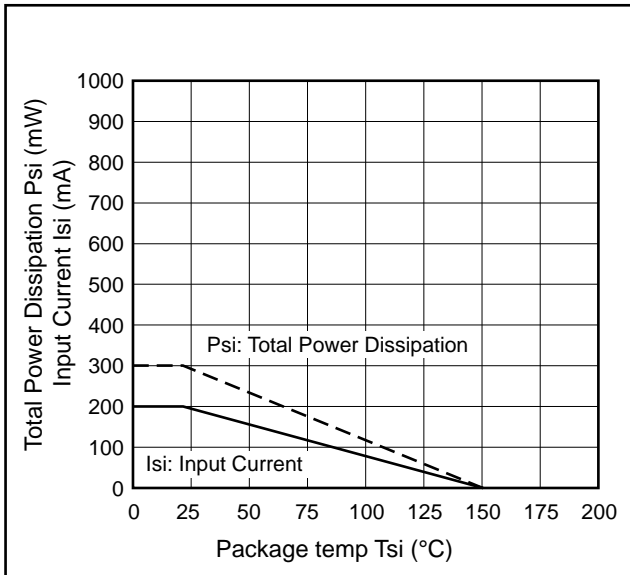
2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

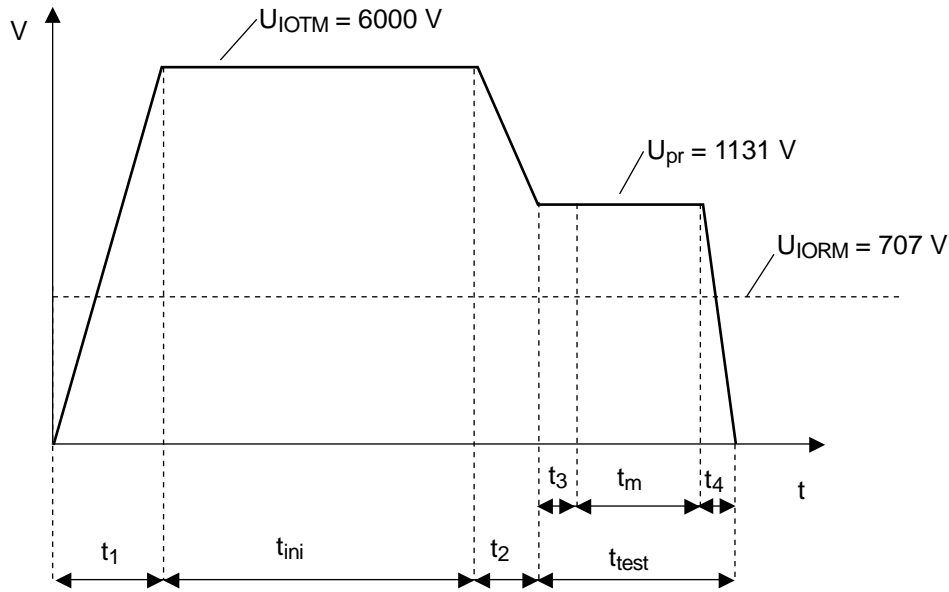
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{IORM}, P_d < 5 \text{ pC}$	U_{IORM} U_{pr}	707 1 131	V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}, P_d < 5 \text{ pC}$	U_{pr}	1 326	V_{peak}
Highest permissible overvoltage	U_{IOTM}	6 000	V_{peak}
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	175	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		III a	
Storage temperature range	T_{stg}	- 55 to +125	°C
Operating temperature range	T_A	- 40 to +100	°C
Isolation resistance, minimum value $V_{IO} = 500 \text{ V dc at } T_A = 25 \text{ °C}$ $V_{IO} = 500 \text{ V dc at } T_A \text{ MAX. at least } 100 \text{ °C}$	Ris MIN. Ris MIN.	10^{12} 10^{11}	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I_F , $P_{si} = 0$) Power (output or total power dissipation) Isolation resistance $V_{IO} = 500 \text{ V dc at } T_A = T_{si}$	T_{si} I_{si} P_{si} Ris MIN.	150 200 300 10^9	°C mA mW Ω

Dependence of maximum safety ratings with package temperature

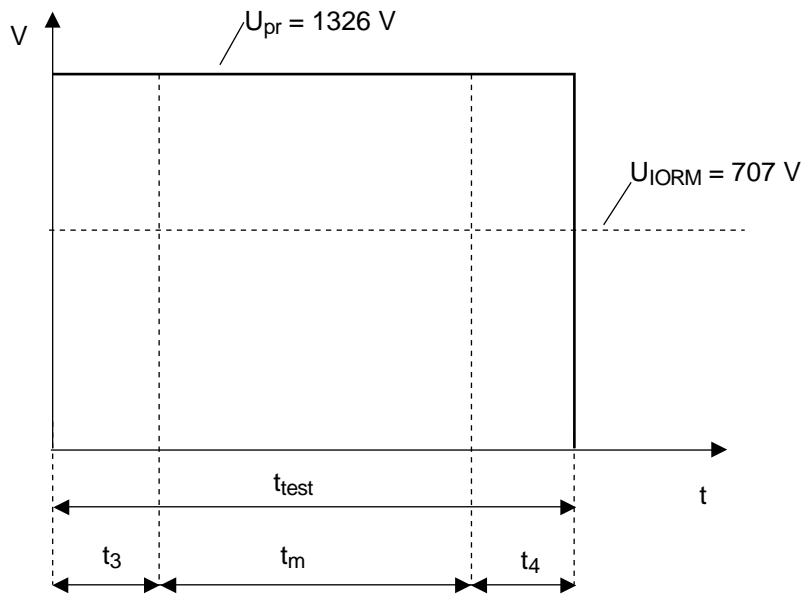


Method a) Destructive Test, Type and Sample Test



$t_1, t_2 = 1\text{ to }10\text{ sec}$
 $t_3, t_4 = 1\text{ sec}$
 $t_m(\text{PARTIAL DISCHARGE}) = 10\text{ sec}$
 $t_{test} = 12\text{ sec}$
 $t_{ini} = 60\text{ sec}$

Method b) Non-destructive Test, 100% Production Test



$t_3, t_4 = 0.1\text{ sec}$
 $t_m(\text{PARTIAL DISCHARGE}) = 1.0\text{ sec}$
 $t_{test} = 1.2\text{ sec}$

Caution	GaAs Products	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none">• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.<ol style="list-style-type: none">1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.• Do not burn, destroy, cut, crush, or chemically dissolve the product.• Do not lick the product or in any way allow it to enter the mouth.
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